

Supporting Information for

Controllable growth of two-dimensional SnSe₂ flakes with screw dislocations and fractal structures

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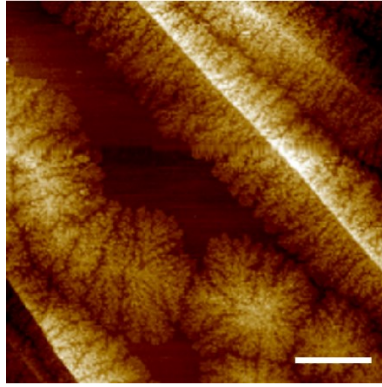


Fig. S1 AFM image of SnSe₂ flakes grown on HOPG with substrate temperature of 100 °C. Scale bar, 300 nm.

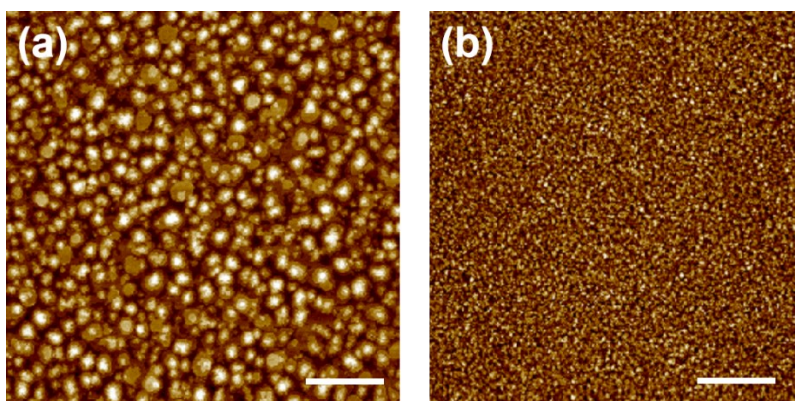


Fig. S2 AFM images of SnSe₂ flakes grown on mica substrates with substrate temperature of 180 °C (a) and 160 °C (b), respectively. Scale bars, 200 nm.